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BLM8G0710S-60PB; BLM8G0710S-60PBG LDMOS 2-stage power MMIC

AMPLEON

Rev. 2 — 22 March 2016

Product data sheet

Product profile

1.1 General description

The BLM8G0710S-60PB(G) is a dual section, 2-stage power MMIC using Ampleon's state of the art GEN8 LDMOS technology. This multiband device is perfectly suited as general purpose driver or small cell final in the frequency range from 700 MHz to 1000 MHz. Available in gull wing or straight lead outline.

Table 1. **Performance**

Typical RF performance at T_{case} = 25 °C.

Test signal: 3GPP test model 1; 64 DPCH; PAR = 9.9 dB at 0.01% probability on CCDF; per section unless otherwise specified in a class-AB production circuit.

Test signal	f	V _{DS}	P _{L(AV)}	G _p	η_{D}	ACPR _{5M}
	(MHz)	(V)	(W)	(dB)	(%)	(dBc)
single carrier W-CDMA	957.5	28	6	34.7	26	-40

1.2 Features and benefits

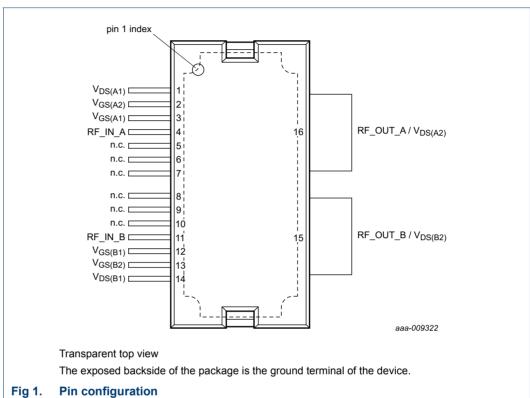
- Designed for broadband operation (frequency 700 MHz to 1000 MHz)
- High section-to-section isolation enabling multiple combinations
- Integrated temperature compensated bias
- Biasing of individual stages is externally accessible
- Integrated ESD protection
- Excellent thermal stability
- High power gain
- On-chip matching for ease of use
- Compliant to Directive 2002/95/EC, regarding restriction of hazardous substances (RoHS)

1.3 Applications

- RF power MMIC for W-CDMA base stations in the 700 MHz to 1000 MHz frequency range. Possible circuit topologies are the following as also depicted in Section 8.1:
 - Dual section or single ended
 - Dohertv
 - Quadrature combined
 - Push-pull

Pinning information 2.

Pinning 2.1



2.2 Pin description

Pin description Table 2.

Symbol	Pin	Description
V _{DS(A1)}	1	drain-source voltage of section A, driver stage (A1)
V _{GS(A2)}	2	gate-source voltage of section A, final stage (A2)
V _{GS(A1)}	3	gate-source voltage of section A, driver stage (A1)
RF_IN_A	4	RF input section A
n.c.	5	not connected
n.c.	6	not connected
n.c.	7	not connected
n.c.	8	not connected
n.c.	9	not connected
n.c.	10	not connected
RF_IN_B	11	RF input section B
V _{GS(B1)}	12	gate-source voltage of section B, driver stage (B1)
V _{GS(B2)}	13	gate-source voltage of section B, final stage (B2)
V _{DS(B1)}	14	drain-source voltage of section B, driver stage (B1)

Table 2. Pin description ...continued

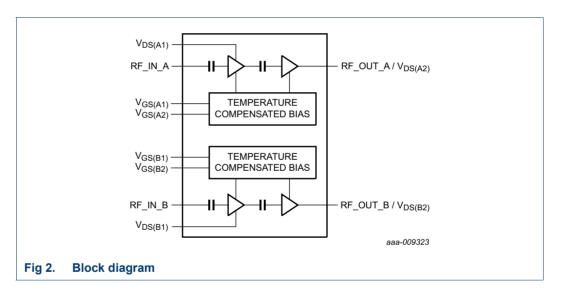
Symbol	Pin	Description
RF_OUT_B/V _{DS(B2)}	15	RF output section B / drain-source voltage of section B, final stage (B2)
RF_OUT_A/V _{DS(A2)}	16	RF output section A / drain-source voltage of section A, final stage (A2)
GND	flange	RF ground

3. Ordering information

Table 3. Ordering information

Type number	Package							
	Name	Description Version						
BLM8G0710S-60PB	HSOP16F	plastic, heatsink small outline package; 16 leads (flat)	SOT1211-2					
BLM8G0710S-60PBG	HSOP16	OP16 plastic, heatsink small outline package; 16 leads SOT1212						

4. Block diagram



5. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	65	V
V_{GS}	gate-source voltage		-0.5	+13	V
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature	[1]	-	225	°C
T _{case}	case temperature		-	150	°C

^[1] Continuous use at maximum temperature will affect the reliability. For details refer to the online MTF calculator.

6. Thermal characteristics

Table 5. Thermal characteristics

Measured for total device.

Symbol	Parameter	Conditions	Value	Unit
R _{th(j-c)}	thermal resistance from junction to case	final stage; T _{case} = 90 °C; P _L = 5 W	0.9	K/W
		driver stage; T _{case} = 90 °C; P _L = 5 W	3.7	K/W

^[1] When operated with a CW signal.

7. Characteristics

Table 6. DC characteristics

 T_{case} = 25 °C; per section unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Final stag	ge				<u> </u>		
V _{(BR)DSS}	drain-source breakdown voltage	V_{GS} = 0 V; I_{D} = 482 μ A		65	-	-	V
V_{GSq}	gate-source quiescent voltage	V _{DS} = 28 V; I _D = 240 mA		1.5	2	2.7	V
		V _{DS} = 28 V; I _D = 240 mA	<u>[1]</u>	1.7	2.65	3.6	V
$\Delta I_{Dq}/\Delta T$	quiescent drain current variation with temperature	-40 °C ≤ T _{case} ≤ +85 °C	[1]	-	1	-	%
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 28 V		-	-	1.4	μΑ
I _{DSX}	drain cut-off current	V _{GS} = 5.65 V; V _{DS} = 10 V		-	8.3	-	Α
I _{GSS}	gate leakage current	V _{GS} = 1.0 V; V _{DS} = 0 V		-	-	140	nA
Driver sta	age						_
V _{(BR)DSS}	drain-source breakdown voltage	V _{GS} = 0 V; I _D = 120.6 μA		65	-	-	V
V_{GSq}	gate-source quiescent voltage	V _{DS} = 28 V; I _D = 60 mA		1.5	2	2.7	V
		V_{DS} = 28 V; I_{D} = 60 mA	[2]	1.7	2.65	3.6	V
Δl _{Dq} /ΔT	quiescent drain current variation with temperature	-40 °C ≤ T _{case} ≤ +85 °C	[2]	-	1	-	%
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 28 V		-	-	1.4	μΑ
I _{DSX}	drain cut-off current	V _{GS} = 5.65 V; V _{DS} = 10 V		-	2.1	-	Α
I _{GSS}	gate leakage current	V _{GS} = 1.0 V; V _{DS} = 0 V		-	-	140	nA

^[1] In production circuit with 1.3 $k\Omega$ gate feed resistor.

Table 7. RF Characteristics

Typical RF performance at T_{case} = 25 °C; V_{DS} = 28 V; I_{Dq1} = 60 mA (driver stage); I_{Dq2} = 240 mA (final stage); $P_{L(AV)}$ = 6 W; unless otherwise specified, measured in an Ampleon wideband straight lead production circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Test sign	al: single carrier W-CDMA [1]					
Gp	power gain	f = 730.5 MHz	-	35.6	-	dB
		f = 957.5 MHz	33.2	34.7	36.2	dB
η_{D}	drain efficiency	f = 730.5 MHz	-	23.4	-	%
		f = 957.5 MHz	21	26	-	%

BLM8G0710S-60PB_S-60PBG

^[2] In production circuit with 1.2 k Ω gate feed resistor.

Table 7. RF Characteristics ...continued

Typical RF performance at T_{case} = 25 °C; V_{DS} = 28 V; I_{Dq1} = 60 mA (driver stage); I_{Dq2} = 240 mA (final stage); $P_{L(AV)}$ = 6 W; unless otherwise specified, measured in an Ampleon wideband straight lead production circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
RLin	input return loss	f = 957.5 MHz	-	-17	-10	dB
ACPR _{5M}	adjacent channel power ratio	f = 730.5 MHz	-	-39.5	-	dBc
	(5 MHz)	f = 957.5 MHz	-	-40	-34.5	dBc
PARO	output peak-to-average ratio	f = 730.5 MHz	-	8	-	dB
		f = 957.5 MHz	6.7	8	-	dB
Test signa	al: CW [2]					
$\Delta\phi_{\text{S21}}$	phase response difference	between sections	-10	-	+10	deg
$\Delta s_{21} ^2$	insertion power gain difference	between sections	-0.5	-	+0.5	dB

^{[1] 3}GPP test model 1; 64 DPCH; PAR = 9.9 dB at 0.01% probability on CCDF.

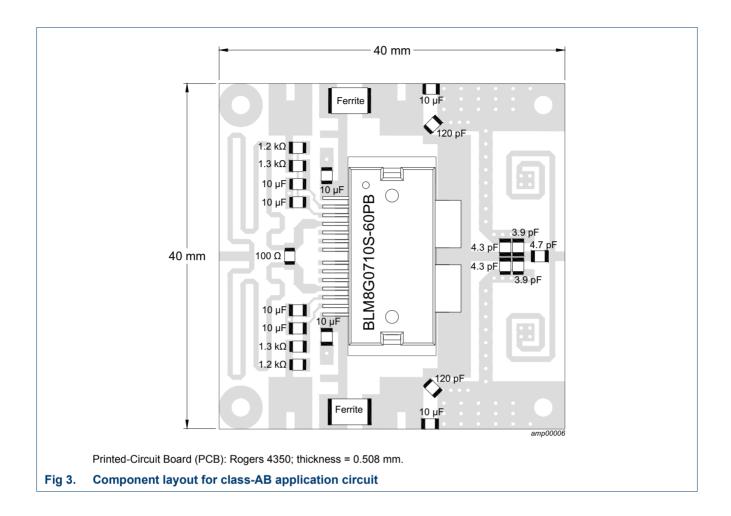
8. Application information

Table 8. Typical performance

Test signal: 1-tone pulsed CW; RF performance at $T_{case} = 25$ °C; $V_{DS} = 28$ V; $I_{Dq} = 600$ mA unless otherwise specified, measured in an Ampleon wideband f = 700 MHz to 1000 MHz class AB application circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
P _{L(1dB)}	output power at 1 dB gain compression	f = 800 MHz	-	74	-	W
η_{D}	drain efficiency	at P _{L(1dB)} ; f = 800 MHz	-	58.4	-	%
G _p	power gain	P _{L(AV)} = 11.2 W; f = 800 MHz	-	36.5	-	dB
B _{video}	video bandwidth	2-tone CW; P _{L(AV)} = 40 W; f = 881.5 MHz	-	154	-	MHz
G _{flat}	gain flatness	P _{L(AV)} = 11.2 W; f = 700 MHz to 1000 MHz	-	0.3	-	dB
ΔG/ΔΤ	gain variation with temperature	f = 800 MHz	-	0.03	-	dB/°C
s ₁₂ ²	isolation	between sections A and B; P _{L(AV)} = 8 W; f = 800 MHz	-	24.5	-	dB
K	Rollett stability factor	T = -40 °C; f = 0.1 GHz to 3 GHz	-	>1.2	-	

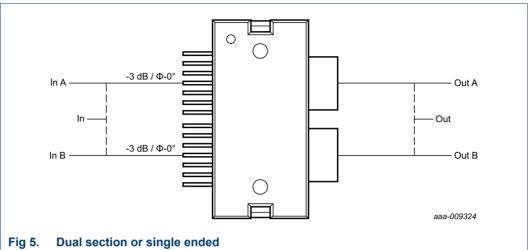
^[2] f = 957.5 MHz.



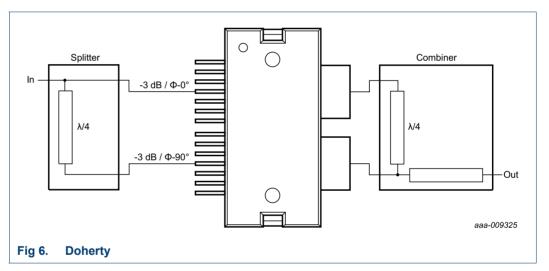
Product data sheet

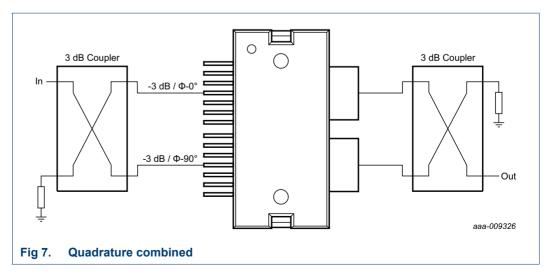
BLM8G0710S-60PB(G) **LDMOS 2-stage power MMIC**

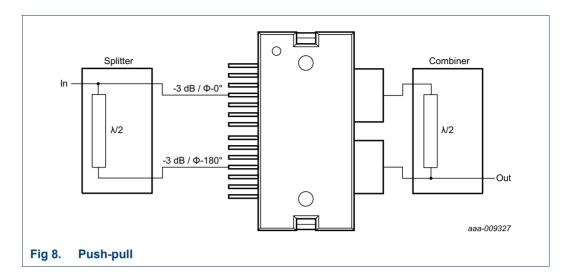
8.1 Possible circuit topologies



rig 5. Duai section of single ended







8.2 Ruggedness in class-AB operation

The BLM8G0710S-60PB and BLM8G0710S-60PBG are capable of withstanding a load mismatch corresponding to VSWR = 30 : 1 through all phases under the following conditions: V_{DS} = 32 V; I_{Dq1} = 60 mA; I_{Dq2} = 192 mA; P_i = 13 dBm, P_i is measured at CW and corresponding to $P_{L(3dB)}$ under Z_S = 50 Ω ; f = 840 MHz.

8.3 Impedance information

Table 9. Typical impedance tuned for maximum output power

Measured load-pull data per section; test signal: pulsed CW; T_{case} = 25 °C; V_{DS} = 28 V; I_{Dq1} = 60 mA; I_{Dq2} = 240 mA; I_{p} = 100 μs; δ = 10 %; I_{p} = 50 I_{p} . Typical values unless otherwise specified.

	tuned for m	aximum o	utput p	ower		tuned for maximum power added efficiency					
f	Z _L	G _{p(max)}	PL	η _{add}	AM-PM conversion	Z _L	G _{p(max)}	PL	η _{add}	AM-PM conversion	
(MHz)	(Ω)	(dB)	(W)	(%)	(deg)	(Ω)	(dB)	(W)	(%)	(deg)	
BLM8G	0710S-60PB						,		'		
700	3.0 + j2.1	36.1	47.2	55.1	2.4	4.2 + j5.2	37.6	45.3	65.7	-1.5	
720	3.0 + j1.7	35.9	47.3	53.4	2.5	4.4 + j5.0	37.8	45.4	64.6	-1.0	
740	3.0 + j1.7	35.8	47.4	54.8	3.0	4.2 + j4.5	37.5	45.7	64.7	-0.2	
760	3.0 + j1.3	35.4	47.4	53.5	3.0	4.1 + j4.8	37.2	45.4	64.3	-0.9	
780	3.3 + j1.3	35.3	47.5	55.0	2.4	4.0 + j4.4	37.0	45.7	63.7	-1.3	
800	3.2 + j0.9	35.2	47.5	53.8	3.1	3.9 + j4.2	37.0	45.8	64.0	-1.0	
820	3.3 + j1.0	35.0	47.5	54.9	2.4	4.1 + j3.8	36.7	46.0	63.6	-0.1	
840	3.4 + j0.5	34.8	47.5	53.2	2.3	3.8 + j4.0	36.8	45.7	63.4	-1.3	
860	3.5 + j0.5	34.7	47.5	53.8	2.1	3.8 + j3.8	36.7	45.7	63.1	-1.2	
880	3.4 + j0.4	34.8	47.4	53.2	1.8	4.0 + j3.5	36.7	45.9	63.1	-0.3	
900	3.4 + j0.3	34.7	47.4	53.4	2.1	3.7 + j3.6	36.8	45.7	63.0	-0.9	
920	3.4 + j0.4	34.7	47.4	54.4	1.4	3.8 + j3.7	36.8	45.5	63.0	-0.5	
940	3.5 + j0.0	34.5	47.3	52.9	1.1	3.5 + j3.2	36.6	45.7	62.3	-0.5	
960	3.5 – j0.1	34.2	47.3	52.7	1.3	3.5 + j3.1	36.4	45.7	62.0	-0.3	
980	3.5 – j0.1	34.2	47.3	53.9	0.4	3.4 + j2.8	36.2	45.8	62.2	-1.0	

BLM8G0710S-60PB_S-60PBG

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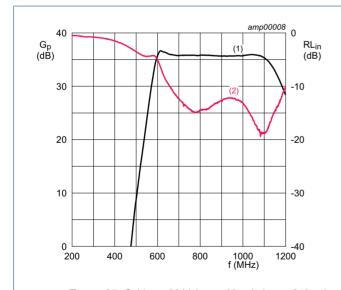
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Table 9. Typical impedance tuned for maximum output power ...continued

Measured load-pull data per section; test signal: pulsed CW; T_{case} = 25 °C; V_{DS} = 28 V; I_{Dq1} = 60 mA; I_{Dq2} = 240 mA; I_{pq} = 100 μs; δ = 10 %; I_{pq} = 50 Ω . Typical values unless otherwise specified.

	tuned for m	tuned for maximum output power						ower a	dded effic	iency
f	Z _L	G _{p(max)}	PL	η _{add}	AM-PM conversion	Z _L	G _{p(max)}	PL	η _{add}	AM-PM conversion
(MHz)	(Ω)	(dB)	(W)	(%)	(deg)	(Ω)	(dB)	(W)	(%)	(deg)
BLM8G	0710S-60PBG	;			"		1			"
700	3.0 + j0.6	36.3	47.5	55.1	0.3	4.5 + j3.6	37.7	45.8	66.1	-3.2
720	3.0 + j0.6	36.4	47.5	55.6	0.6	4.4 + j3.1	37.7	46.1	65.7	-2.2
740	2.9 + j0.3	35.9	47.6	54.6	1.9	4.1 + j3.4	37.3	45.8	65.4	-2.0
760	3.0 + j0.2	35.6	47.7	56.0	0.6	4.4 + j2.8	37.0	46.1	65.1	-2.2
780	3.3 – j0.1	35.5	47.7	55.9	0.9	4.3 + j2.9	37.0	46.0	64.7	-2.9
800	3.3 – j0.5	35.4	47.7	54.4	0.8	3.9 + j2.6	37.0	46.1	64.4	-3.2
820	3.3 – j0.5	35.8	47.7	55.2	1.3	4.1 + j2.3	37.3	46.2	64.0	-1.8
840	3.3 – j0.5	35.5	47.6	55.4	1.3	4.1 + j2.1	36.6	46.3	63.7	-1.3
860	3.5 – j0.9	34.5	47.7	54.9	0.6	3.8 + j2.0	35.9	46.3	63.7	-2.5
880	3.4 – j1.0	34.7	47.6	54.2	-0.1	3.6 + j2.0	36.4	46.1	63.1	-3.2
900	3.4 – j1.2	34.8	47.6	54.2	0.0	3.7 + j1.8	36.5	46.1	63.3	-2.7
920	3.4 – j1.1	35	47.6	55.4	-0.4	3.7 + j1.8	36.6	45.9	63.2	-1.9
940	3.5 – j1.4	34.7	47.5	54.7	-0.3	3.8 + j1.6	36.4	46.0	62.8	-1.2
960	3.5 – j1.6	34.4	47.5	54.9	-0.4	3.5 + j1.3	36.1	46.0	62.8	-2.2

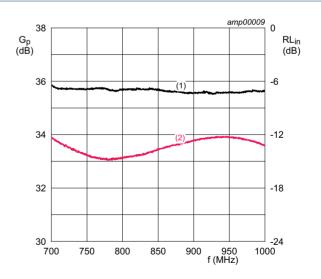
8.4 Graphs



 T_{case} = 25 °C; V_{DS} = 28 V; I_{Dq1} = 60 mA; I_{Dq2} = 240 mA; P_L = 2 W. Per section.

- (1) magnitude of G_p
- (2) magnitude of RLin

Fig 9. Wideband power gain and input return loss as function of frequency; typical values



 T_{case} = 25 °C; V_{DS} = 28 V; I_{Dq1} = 60 mA; I_{Dq2} = 240 mA; P_L = 2 W. Per section.

- (1) magnitude of G_p
- (2) magnitude of RLin

Fig 10. In-band power gain and input return loss as function of frequency; typical values

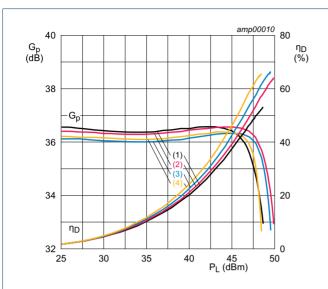
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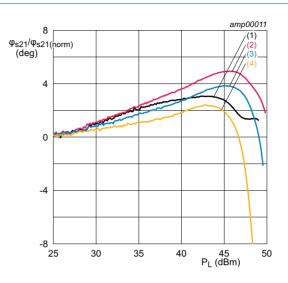
LDMOS 2-stage power MMIC



 T_{case} = 25 °C; V_{DS} = 28 V; I_{Dq1} = 60 mA; I_{Dq2} = 240 mA. Per section.

- (1) f = 700 MHz
- (2) f = 800 MHz
- (3) f = 900 MHz
- (4) f = 1000 MHz

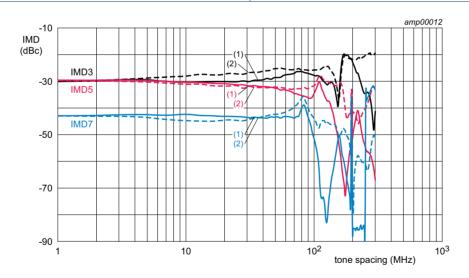
Fig 11. Power gain and drain efficiency as function of output power; typical values



Normalized at P_L = 22 dBm; T_{case} = 25 °C; V_{DS} = 28 V; I_{Dq1} = 60 mA; I_{Dq2} = 240 mA. Per section.

- (1) f = 700 MHz
- (2) f = 800 MHz
- (3) f = 900 MHz
- (4) f = 1000 MHz

Fig 12. Normalized phase response as a function of output power; typical values



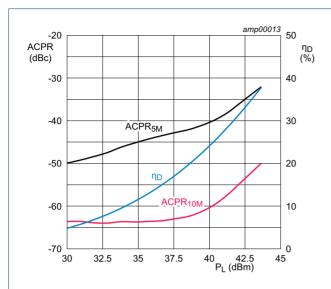
 $T_{case} = 25 \, ^{\circ}\text{C}; V_{DS} = 28 \, \text{V}; I_{Dq1} = 60 \, \text{mA}; I_{Dq2} = 240 \, \text{mA}; f = 881.5 \, \text{MHz}; 2-tone CW, P_L = 20 \, \text{W}. Per section.$

- (1) IMD low
- (2) IMD high

Fig 13. Intermodulation distortion as a function of tone spacing; typical values

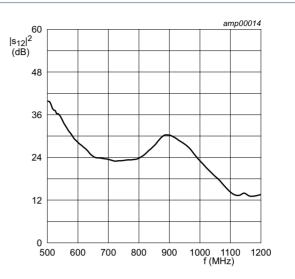
BLM8G0710S-60PB(G)

LDMOS 2-stage power MMIC



 T_{case} = 25 °C; V_{DS} = 28 V; I_{Dq1} = 60 mA; I_{Dq2} = 240 mA: f = 900 MHz; 1-carrier W-CDMA; test model 1; PAR = 9.9 dB at 0.01% probability on CCDF. Per section

Fig 14. Adjacent channel power ratio and drain efficiency as function of output power; typical values



 T_{case} = 25 °C; V_{DS} = 28 V; I_{Dq1} = 40 mA; I_{Dq2} = 260 mA, measured on evaluation board.

Fig 15. Section A to B isolation as a function of frequency; typical values

9. Package outline

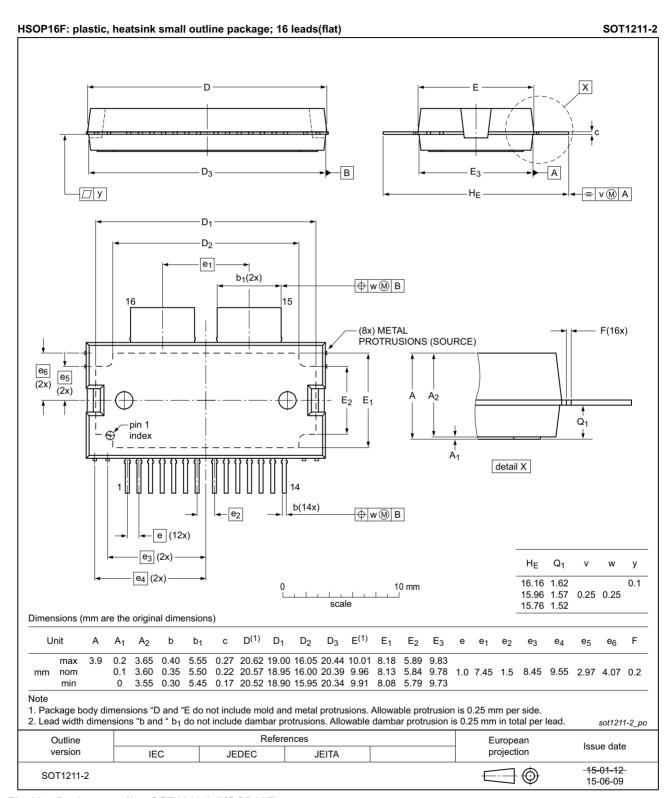


Fig 16. Package outline SOT1211-2 (HSOP16F)

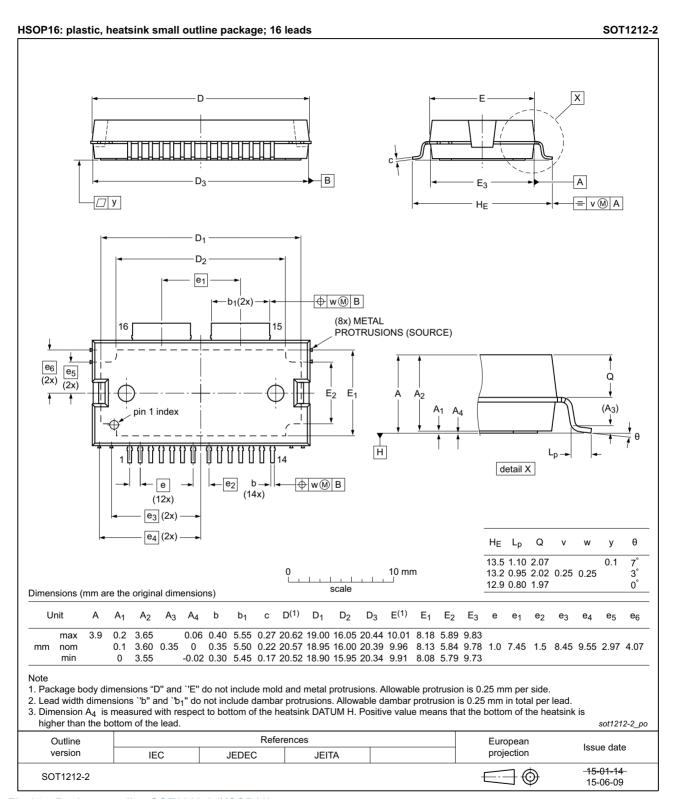


Fig 17. Package outline SOT1212-2 (HSOP16)

10. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

11. Abbreviations

Table 10. Abbreviations

Acronym	Description
AM	Amplitude Modulation
3GPP	3rd Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
ESD	ElectroStatic Discharge
GEN8	Eighth Generation
LDMOS	Laterally Diffused Metal Oxide Semiconductor
MMIC	Monolithic Microwave Integrated Circuit
MTF	Median Time to Failure
PAR	Peak-to-Average Ratio
PM	Phase Modulation
VSWR	Voltage Standing-Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

12. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLM8G0710S-60PB_S-60PBG v.2	20160322	Product data sheet	-	BLM8G0710S-60PB_ S-60PBG v.1
Modifications:	• Figure 16 or	n page 13: figure updated		
• Figure 17 on page		n page 14: figure updated		
BLM8G0710S-60PB_S-60PBG v.1	20160225	Product data sheet	-	-

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.ampleon.com.

13.2 Definitions

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14. Contact information

For more information, please visit: http://www.ampleon.com

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